

Trans IGBT Chip N-CH 1700V 75A 350mW 3-Pin(3+Tab) TO-247AD

Manufacturer: <u>Littelfuse Inc</u>

Package/Case: TO-247

Product Type: Thyristors

Lifecycle: Active Images



Images are for reference only

Inquiry

General Description

BiMOSFETs are devices, which have combined strengths of MOSFETs and IGBTs. Non-epitaxial construction and new fabrication processes were used in making BiMOSFETs a great success. These high voltage devices are ideal for parallel operation due to the positive voltage temperature coefficient of both of its saturation voltage, and the forward voltage drop of its intrinsic diode. Furthermore, this "free" intrinsic body diode serves as a protection diode, providing an alternative path for the inductive load current during device turn-off, preventing high Ldi/dt voltage transients from inflicting damage to the device.

Key Features	Application	
High blocking voltage	Radar transmitter power supplies	
High power density	Radar pulse modulators	
High current handling capability	Capacitor discharge circuits	
Low conduction losses		
MOS gate turn on for drive simplicity	High voltage power supplies	
International standard and proprietary ISOPLUSTM packages	AC switches	
Benefits:	HV circuit breakers	
Eliminates multiple series-parallel lower voltage, lower current rateddevices	Pulser circuits	
Simpler system design	TT 1 10 10 10 10 10 10 10 10 10 10 10 10 1	
Improved reliability	High voltage test equipment	
Reduced component count	Laser & X-ray generators	
Reduced system cost		

Recommended For You

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TO-247 MODULE TO-247

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IXGP8N100 IXTQ460P2 IXGR48N60C3D1

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